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## Temperature dependence of commercial 4H-SiC UV Schottky photodiodes for X-ray detection and spectroscopy

Shifan Zhao, Grammatiki Lioliou, Anna Barnett

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Corrigendum

### Corrigendum to 'Temperature dependence of commercial 4H-SiC UV Schottky photodiodes for X-ray detection and spectroscopy' [Nucl. Instrum. Methods Phys. Res. A 859 (2017) 76–82]



#### S. Zhao \*, G. Lioliou, A.M. Barnett

Semiconductor Materials and Devices Laboratory, Department of Engineering and Design, School of Engineering and Informatics, University of Sussex, Falmer, Brighton BN1 9QT, UK

The authors have been informed by the manufacturer of the photodiodes (SGlux SolGel Technologies GmbH, Berlin, Germany) that the photodiodes reported had Ohmic contacts rather than Schottky contacts.

The authors apologize for any inconvenience caused.

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E-mail address: Shifan.Zhao@sussex.ac.uk (S. Zhao).

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